

L Number	Hits	Search Text	DB	Time stamp
22	4210514	@pd>20020514	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
23	1	118/\$.ccls. and ((illuminat\$ near5 visual) same (semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
24	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness) and (photoresist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
25	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
26	397	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
27	5122	(118/320.ccls. or 118/326.ccls. or 118/712.ccls. or 118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
28	4083	(222/113.ccls. or 362/231.ccls. or 355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
29	3708	156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
30	451303	process and chamber andnon-reflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
31	4557	(362/145.ccls. or 362/147.ccls. or 362/149.ccls. or 362/154.ccls. or 362/155.ccls. or 362/800.ccls. or 362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
32	174	118/677	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
33	1	(118/713.ccls.) and (illumination near3 intensity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41

34	2168	356/\$.ccls. and (illuminat\$4 near3 intens\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:41
72	9851	"advanced micro devices"	USPAT; US-PGPUB	2004/07/21 18:42
81	2594	250/205	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:42
83	112	((250/205).CCLS.) and (coating or dispensing or coat or dispense)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:43
21	965	subramanian.in.	USPAT; US-PGPUB	2004/07/21 18:43
35	339	@pd>20020514 and (118/50.ccls. or 118/52.ccls. or 118/50.1.ccls. or 118/56.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:43
36	626	@pd>20020514 and (118/320.ccls. or 118/326.ccls. or 118/712.ccls. or 118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:44
37	1351	@pd>20020514 and (222/113.ccls. or 362/231.ccls. or 355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:44
38	588	@pd>20020514 and (156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
39	1001	@pd>20020514 and (362/145.ccls. or 362/147.ccls. or 362/149.ccls. or 362/154.ccls. or 362/155.ccls. or 362/800.ccls. or 362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
40	17	118/\$.ccls. and ((visual near3 inspection) same (chuck or holder or table))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
41	11	118/\$.ccls. and ((visual near3 inspection) same (semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
42	97	118/\$.ccls. and ((illuminat\$) same (semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
43	191	118/\$.ccls. and ((illuminat\$) same (chamber))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45

44	717	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode" or "light emitting diodes") and controller	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
45	1	"5843527".PN.	USPAT	2004/07/21 18:45
46	222	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode" or "light emitting diodes") and (controller same (input or output))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
47	1	6122042.pn.	USPAT	2004/07/21 18:45
48	1	6122042.pn. and (coat or coating)	USPAT	2004/07/21 18:45
49	61	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness) and photoresist	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:45
50	50	(118/\$.ccls.) and (photodiode) and (thickness) and controller	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
51	11	"5985357"	USPAT	2004/07/21 18:46
52	97	process and chamber and anti-reflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
53	1	4713140.pn.	USPAT	2004/07/21 18:46
54	1	4696209.pn.	USPAT	2004/07/21 18:46
55	1	4227347.pn.	USPAT	2004/07/21 18:46
56	13	process and chamber and non-reflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
57	4	process and chamber and nonreflective and 118/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
58	1569	438/16	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
59	162	438/16 and reflectivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
60	23	438/16 and (illumination near3 intensity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
61	28	438/16 and (illuminat\$4 near3 intens\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46

62	5	(118/712.ccls.) and (illumination near3 intensity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:46
63	679	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:47
64	347	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:47
65	18	"6016562"	USPAT	2004/07/21 18:47
66	1398	((118/712) or (118/713)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:47
67	1	("6031607").PN.	USPAT	2004/07/21 18:47
68	8	356/\$.ccls. and (adjustable near3 intens\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:48
69	26	356/\$.ccls. and (adjustable near3 illuminat\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:48
70	88	356/\$.ccls. and (variable near3 intens\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:48
71	1	("6376013").PN.	USPAT	2004/07/21 18:48
73	165	subramanian.in. and (advanced near2 micro)	USPAT; US-PGPUB	2004/07/21 18:48
74	7444	advanced.asn. and micro.asn. and devices.asn.	USPAT; US-PGPUB	2004/07/21 18:51
75	154	advanced.asn. and micro.asn. and devices.asn. and (396/\$.ccls. or 118/\$.ccls. or 427/\$.ccls. or 131/\$.ccls.)	USPAT; US-PGPUB	2004/07/21 18:51
76	8	((("5968268") or ("5845170") or ("5720814") or ("5718992") or ("5393624") or ("5366757") or ("5127362") or ("5089305")).PN.	USPAT	2004/07/21 18:51
77	14	((("5962070") or ("5942037") or ("5885755") or ("5885661") or ("5826130") or ("5820677") or ("5678116") or ("5625433") or ("5555234") or ("5474877") or ("5275658") or ("5089305") or ("4997552") or ("4564280")).PN.	USPAT	2004/07/21 18:51
78	1	"20020029744"	US-PGPUB	2004/07/21 18:51
79	10	356/\$.ccls. and (compensation near3 illuminat\$4) and semiconductor and thickness	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:51
80	97	356/455	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:51

82	69	(356/455).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:51
84	127	((250/205).CCLS.) and (coating or dispensing or coat or dispense)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:51
85	1214	(250/205).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/21 18:52